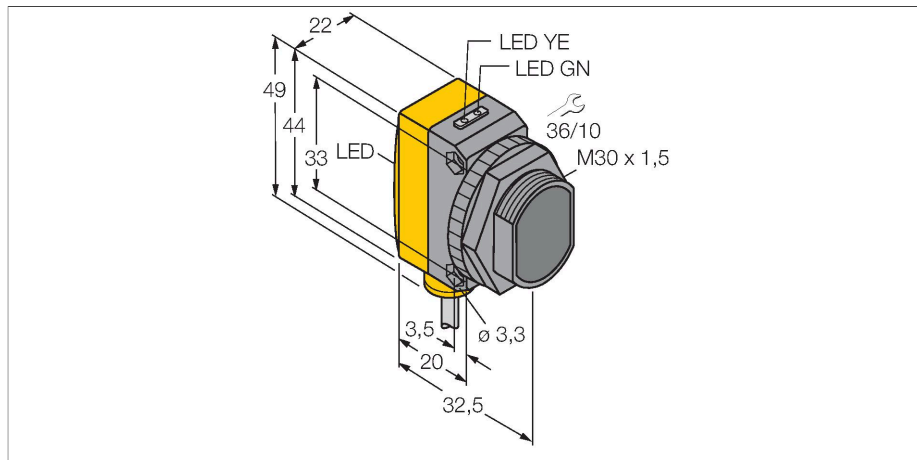


QS30E

Photoelectric Sensor – Opposed Mode Sensor (Emitter)



Technical data

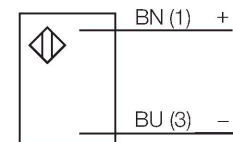
Type	QS30E
ID	3073081
Optical data	
Function	Opposed mode sensor
Operating mode	Emitter
Light type	IR
Wavelength	875 nm
Range	0...60000 mm
Electrical data	
Operating voltage	10...30 VDC
Residual ripple	< 10 % U _{ss}
No-load current	≤ 70 mA
Short-circuit protection	yes
Reverse polarity protection	yes
Readiness delay	≤ 100 ms
Response time typical	< 5 ms
Mechanical data	
Design	Rectangular with thread, QS30
Dimensions	Ø 30 x 35 x 22 x 49 mm
Housing material	Plastic, Thermoplastic material, Yellow
Lens	plastic, Acrylic
Electrical connection	Cable, 2 m, PVC
Number of cores	2
Core cross-section	0.5 mm ²
Ambient temperature	-20...+70 °C
Protection class	IP67
Power-on indication	LED, Green



Features

- Cable, PVC, 2 m
- Protection class IP67
- LED all-round visible
- Operating voltage: 10...30 VDC

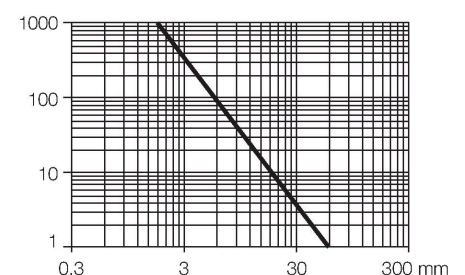
Wiring diagram



Functional principle

Opposed mode sensors consist of an emitter and receiver. They are installed opposite to each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Large distance operation is possible due to an excellent light/dark contrast and an extremely high excess gain.

Excess gain curve
Excess gain in relation to the distance



Technical data

Error indication	LED, green
Excess gain indication	LED
Tests/approvals	
MTTF	402 years acc. to SN 29500 (Ed. 99) 40 °C
Approvals	CE

Accessories

